## What is claimed is:

- A method of manufacturing a liquid crystal display (LCD) device, comprising:
   forming a photo-sensitive layer over a substrate;
   forming a photo-insensitive layer over the photo-sensitive layer;
   exposing a portion of the photo-sensitive layer via a photo-mask to a radiation source;
   and
   contacting the portion of the photo-sensitive layer using a developing solution.
- 10 2. The method of claim 1, wherein said contacting dissolves the portion of the photosensitive layer and removes the portion of the photo-insensitive layer overlying the portion of the photo-sensitive layer together.
  - 3. The method of claim 1, wherein the photo-insensitive layer is formed of photo-insensitive resin.
  - 4. The method of claim 3, wherein the photo-insensitive resin is selected from the group consisting of photo-insensitive PFCB, photo-insensitive BCB, photo-insensitive polyimide and photo-insensitive SOG.
  - 5. The anethod of claim 1, wherein the radiation source is electron beam radiation, x-ray radiation, or ultraviolet radiation.
  - 6. The method of claim 1, wherein the developing solution includes an alkaline solution.
  - 7. The method of claim 6, wherein said alkaline solution is TMAH.
  - 8. The method of claim 1, wherein the photo-sensitive layer is formed of photo-sensitive resin.
  - 9. The method of claim 8, wherein the photo-sensitive resin is selected from the group consisting of photo-sensitive acrylic resin, photo-sensitive BCB, photo-sensitive PFCB and photo-sensitive polyimide.

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- 10. The method of claim 1, wherein the thickness of the photo-sensitive layer is between approximately 0.1 and 8  $\mu$ m.
- The method of claim 1, wherein the thickness of the photo-insensitive layer is
  between approximately 0.1 and 8 μm.
  - 12. The method of claim 1, wherein the thickness ratio of the photo-insensitive layers to the total thickness of the photo-sensitive layer and photo-insensitive layer is not more than approximately 50%.
  - 13. The method of claim 1, wherein the dielectric constant of the photo-sensitive layer is between approximately 2.5 and 4.0.
    - 14. The method of claim 1, wherein the dielectric constant of the photo-insensitive layer is between approximately 1.5 and 3.5.
    - 15. The method of claim 1, wherein the combined dielectric constant of the photosensitive layer and the photo-insensitive layer is between approximately 1.5 and 3.5.
    - 16. The method of claim 1, wherein said forming the photo-insensitive layer and said forming the photo-sensitive layer are performed consecutively.
    - 17. The method of claim 1, further comprising, curing the photo-insensitive layer and the photo-sensitive layer at the same time.
    - 18. The method of claim 17, further comprising: forming a transparent electrode layer overlying the resulting structure.
- 19. A method of manufacturing a liquid crystal display (LCD) device, comprising:

  forming a gate bus line over an insulating substrate;

  forming a gate insulator over the gate bus line;

  forming a drain electrode over the gate insulator;

  forming a photo-sensitive layer over a substrate;

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forming a photo-insensitive layer over the photo-sensitive layer;
exposing a portion of the photo-sensitive layer via a photomask to a radiation source,
contacting the portion of the photosensitive layer using a developing solution through
the photo-insensitive layer to remove the portion of the photo-sensitive layer and an
immediately overlying portion of the photo-insensitive layer;

curing the photo-insensitive layer and the photo-sensitive layer at the same time; and forming a transparent electrode layer overlying the resulting structure.

- 20. The method of claim 19, wherein the transparent electrode layer includes indium tin oxide (ITO).
  - 21. The method of claim 20, the insulating substrate is formed of transparent material.
  - 22. The method of claim 19, wherein photo-insensitive layer is formed of photo-insensitive resin.
  - 23. The method of claim 21, wherein the photo-insensitive resin is selected from the group consisting of photo-insensitive PFCB, photo-insensitive BCB, photo-insensitive polyimide and photo-insensitive SOG.
  - 24. The method of claim18, wherein the developing solution comprises an alkaline solution.
  - 25. The method of claim 24, wherein said alkaline solution is TMAH.
  - 26. The method of claim 18, wherein the photo-sensitive layer is formed of photo-sensitive resin.
- 27. The method of claim 26, wherein the photo-sensitive resin is one selected from the group consisting of photo-sensitive acrylic resin, photo-sensitive BCB, photo-sensitive PFCB and photo-sensitive polyimide.

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- 28. The method of claim 19, wherein the thickness of the photo-sensitive layer is between approximately 0.1 and 8 µm and the thickness of the photo-insensitive layer is between approximately 0.1 and 8 um.
- 29. 5 The method of claim 19, wherein the thickness ratio of the photo-insensitive layers to the total thickness of the photo-sensitive layer and photo-insensitive layer is not more than approximately 50%.
- 30. The method of claim 19, wherein the dielectric constant of the photo-sensitive layer is between approximately 2.5 and 4.0. 10
  - 31. The method of claim 19, wherein the dielectric constant of the photo-insensitive layer is between approximately 1.5 and 3.5.
  - 32. The method of claim 19, wherein the combined dielectric constant of the photosensitive layer and the photo-insensitive layer is between approximately 1.5 and 3.5.
    - 33. The method of claim 19, wherein the photosensitive layer has a thickness of approximately 1.5 µm and photo-insensitive layer has a thickness of approximately 1.5 µm.
    - 34. A liquid crystal display (LCD) device comprising:
      - an insulating substrate,
      - a gate bus line formed overlying the substrate:
      - a gate insulating layer formed over the gate bus line;
      - a drain electrode formed over the gate insulating layer; and
    - a multi-layer interlayer insulator formed overlying the drain electrode, the multi-layer interlayer insulator having a through hole.
- 30 35. The LCD device of claim 34, further comprising:
  - a pixel electrode formed over the multi-layer interlayer insulator including the through hole.

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- 36. The LCD device of claim 34, wherein the multi-layer interlayer insulator comprises a photo-sensitive resin and a photo-insensitive resin overlying the photo-sensitive resin.
- 37. The LCD device of claim 36, wherein the photo-insensitive resin is selected from the group consisting of photo-insensitive PFCB, photo-insensitive BCB, photo-insensitive polyimide and photo-insensitive SOG.
  - The LCD device of claim 36, wherein the photo-sensitive layer is formed of one 38. selected from the group consisting of photo-sensitive acrylic resin, photo-sensitive BCB, photo-sensitive PFCB and photo-sensitive polyimide.
  - 39. The LCD device of claim 34, wherein the thickness of the photo-sensitive layer is between approximately 0.1 and 8 µm.
- 40. The LCD device of claim 34, wherein the thickness of the photo-insensitive layer is between approximately 0.1 and 8 µm.
  - 41. The LCD device of claim 34, wherein the thickness ratio of the photo-insensitive layers to the total thickness of the photo-sensitive layer and photo-insensitive layer is not more than approximately 50%.
  - 42. The LCD device of claim 34, wherein the dielectric constant of the photo-sensitive layer is between approximately 2.5 and 4.0.
- The LCD device of claim 34, wherein the dielectric constant of the photo-insensitive 25 43. layer is between approximately 1.5 and 3.5.
  - 44. The LCD device of claim 34, wherein the combined dielectric constant of the photosensitive layer and the photo-insensitive layer is between approximately 1.5 and 3.5.
  - 45. The LCD device of claim 34, wherein the photosensitive layer has a thickness of approximately 1.5 μm and photo-insensitive layer has a thickness of approximately 1.5 μm.

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- 46. A liquid crystal display (LCD) device comprising:
  - a transparent insulating substrate,
  - a gate bus line formed overlying the substrate;
  - a gate insulating layer formed over the gate bus line;
  - a drain electrode formed over the gate insulating layer;
- a multi-layer insulator formed overlying the drain electrode, the multi-layer interlayer insulator having a through hole; and
- a transparent electrode formed over the multi-layer interlayer insulator including the through hole,

wherein the multi-layer interlayer insulator comprises a photo-sensitive resin and a photo-insensitive resin overlying the photo-sensitive resin.

- 47. The LCD device of claim 46, wherein the photo-insensitive resin is selected from the group consisting of photo-insensitive PFCB, photo-insensitive BCB, photo-insensitive polyimide and photo-insensitive SOG.
- 48. The LCD device of claim 46, wherein the photo-sensitive layer is formed of one selected from the group consisting of photo-sensitive acrylic resin, photo-sensitive BCB, photo-sensitive PFCB and photo-sensitive polyimide.